# BCD-to-Seven Segment Latch/Decoder/Driver for Liquid Crystals

The MC14543B BCD-to-seven segment latch/decoder/driver is designed for use with liquid crystal readouts, and is constructed with complementary MOS (CMOS) enhancement mode devices. The circuit provides the functions of a 4-bit storage latch and an 8421 BCD-to-seven segment decoder and driver. The device has the capability to invert the logic levels of the output combination. The phase (Ph), blanking (BI), and latch disable (LD) inputs are used to reverse the truth table phase, blank the display, and store a BCD code, respectively. For liquid crystal (LC) readouts, a square wave is applied to the Ph input of the circuit and the electrically common backplane of the display. The outputs of the circuit are connected directly to the segments of the LC readout. For other types of readouts, such as light-emitting diode (LED), incandescent, gas discharge, and fluorescent readouts, connection diagrams are given on this data sheet.

Applications include instrument (e.g., counter, DVM etc.) display driver, computer/calculator display driver, cockpit display driver, and various clock, watch, and timer uses.

- Latch Storage of Code
- Blanking Input
- Readout Blanking on All Illegal Input Combinations
- Direct LED (Common Anode or Cathode) Driving Capability
- Supply Voltage Range = 3.0 V to 18 V
- Capable of Driving 2 Low–power TTL Loads, 1 Low–power Schottky TTL Load or 2 HTL Loads Over the Rated Temperature Range
- Pin-for-Pin Replacement for CD4056A (with Pin 7 Tied to V<sub>SS</sub>).
- Chip Complexity: 207 FETs or 52 Equivalent Gates

# **MAXIMUM RATINGS** (Voltages Referenced to $V_{SS}$ ) (Note 2.)

Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage Range	-0.5 to +18.0	V
V <sub>in</sub>	Input Voltage Range, All Inputs	-0.5 to V <sub>DD</sub> + 0.5	V
I <sub>in</sub>	DC Input Current per Pin	±10	mA
P <sub>D</sub>	Power Dissipation, per Package (Note 3.)	500	mW
T <sub>A</sub>	Operating Temperature Range	-55 to +125	°C
T <sub>stg</sub>	Storage Temperature Range	-65 to +150	°C
I <sub>OHmax</sub> I <sub>OLmax</sub>	Maximum Continuous Output Drive Current (Source or Sink)	10 (per Output)	mA
P <sub>OHmax</sub> P <sub>OLmax</sub>	Maximum Continuous Output Power (Source or Sink) (4.)	70 (per Output)	mW

- Maximum Ratings are those values beyond which damage to the device may occur.
- Temperature Derating: Plastic "P and D/DW" Packages: – 7.0 mW/°C From 65°C To 125°C
- 4.  $P_{OHmax} = I_{OH} (V_{OH} V_{DD})$  and  $P_{OLmax} = I_{OL} (V_{OL} V_{SS})$

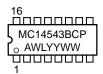


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# MARKING DIAGRAMS



PDIP-16 P SUFFIX CASE 648





SOIC-16 D SUFFIX CASE 751B





SOEIAJ-16 F SUFFIX CASE 966



A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week

#### ORDERING INFORMATION

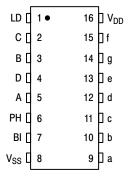
Device	Package	Shipping
MC14543BCP	PDIP-16	2000/Box
MC14543BD	SOIC-16 48/Rail	
MC14543BDR2	SOIC-16	2500/Tape & Reel
MC14543BF	SOEIAJ-16	See Note 1.
MC14543BFEL	SOEIAJ-16	See Note 1.

 For ordering information on the EIAJ version of the SOIC packages, please contact your local ON Semiconductor representative.

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.

# **PIN ASSIGNMENT**



# **TRUTH TABLE**

	lı				nputs					Outputs				
LD	ВІ	Ph*	D	С	В	Α	а	b	С	d	е	f	g	Display
Х	1	0	Х	Χ	Х	Χ	0	0	0	0	0	0	0	Blank
1	0	0	0	0	0	0	1	1	1	1	1	1	0	0
1	0	0	0	0	0	1	0	1	1	0	0	0	0	1
1	0	0	0	0	1	0	1	1	0	1	1	0	1	2
1	0	0	0	0	1	1	1	1	1	1	0	0	1	3
1	0	0	0	1	0	0	0	1	1	0	0	1	1	4
1	0	0	0	1	0	1	1	0	1	1	0	1	1	5
1	0	0	0	1	1	0	1	0	1	1	1	1	1	6
1	0	0	0	1	1	1	1	1	1	0	0	0	0	7
1	0	0	1	0	0	0	1	1	1	1	1	1	1	8
1	0	0	1	0	0	1	1	1	1	1	0	1	1	9
1	0	0	1	0	1	0	0	0	0	0	0	0	0	Blank
1	0	0	1	0	1	1	0	0	0	0	0	0	0	Blank
1	0	0	1	1	0	0	0	0	0	0	0	0	0	Blank
1	0	0	1	1	0	1	0	0	0	0	0	0	0	Blank
1	0	0	1	1	1	0	0	0	0	0	0	0	0	Blank
1	0	0	1	1	1	1	0	0	0	0	0	0	0	Blank
0	0	0	Х	Χ	Χ	Χ				**				**
†	†	†		†			Inverse of Output Combinations				Display as above			
							Α	Above						

X = Don't care

<sup>† =</sup> Above Combinations

<sup>\* =</sup> For liquid crystal readouts, apply a square wave to Ph For common cathode LED readouts, select Ph = 0 For common anode LED readouts, select Ph = 1

<sup>\*\* =</sup> Depends upon the BCD code previously applied when LD = 1

# **ELECTRICAL CHARACTERISTICS** (Voltages Referenced to $V_{SS}$ )

			V <sub>DD</sub>	- 5	5°C		25°C		125	5°C	
Characteristic		Symbol	Vdc	Min	Max	Min	Тур <sup>(5.)</sup>	Max	Min	Max	Unit
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	"0" Level	V <sub>OL</sub>	5.0 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0 0 0	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	Vdc
$V_{in} = 0$ or $V_{DD}$	"1" Level	V <sub>OH</sub>	5.0 10 15	4.95 9.95 14.95	_ _ _	4.95 9.95 14.95	5.0 10 15	_ _ _	4.95 9.95 14.95	_ _ _	Vdc
Input Voltage (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	"0" Level	V <sub>IL</sub>	5.0 10 15		1.5 3.0 4.0		2.25 4.50 6.75	1.5 3.0 4.0		1.5 3.0 4.0	Vdc
$(V_O = 0.5 \text{ or } 4.5 \text{ Vdc})$ $(V_O = 1.0 \text{ or } 9.0 \text{ Vdc})$ $(V_O = 1.5 \text{ or } 13.5 \text{ Vdc})$	"1" Level	V <sub>IH</sub>	5.0 10 15	3.5 7.0 11	_ _ _	3.5 7.0 11	2.75 5.50 8.25	_ _ _	3.5 7.0 11	_ _ _	Vdc
Output Drive Current $ (V_{OH} = 2.5 \text{ Vdc}) $ $ (V_{OH} = 4.6 \text{ Vdc}) $ $ (V_{OH} = 0.5 \text{ Vdc}) $ $ (V_{OH} = 9.5 \text{ Vdc}) $ $ (V_{OH} = 13.5 \text{ Vdc}) $	Source	I <sub>OH</sub>	5.0 5.0 10 10	- 3.0 - 0.64  - 1.6 - 4.2	  -  -  -	- 2.4 - 0.51  - 1.3 - 3.4	- 4.2 - 0.88 - 10.1 - 2.25 - 8.8	  -  -  -	- 1.7 - 0.36  - 0.9 - 2.4		mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 9.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	Sink	I <sub>OL</sub>	5.0 10 10 15	0.64 1.6 — 4.2	_ _ _ _	0.51 1.3 — 3.4	0.88 2.25 10.1 8.8	_ _ _ _	0.36 0.9 — 2.4	_ _ _	mAdc
Input Current		I <sub>in</sub>	15	_	±0.1	_	±0.00001	±0.1	_	±1.0	μAdc
Input Capacitance		C <sub>in</sub>	1	_	1	_	5.0	7.5	_	_	pF
Quiescent Current (Per Package) $V_{in} = 0$ c $I_{out} = 0 \mu A$	or V <sub>DD</sub> ,	I <sub>DD</sub>	5.0 10 15	_ _ _	5.0 10 20	_ _ _	0.005 0.010 0.015	5.0 10 20	_ _ _	150 300 600	μAdc
Total Supply Current (6.) (7.)  (Dynamic plus Quiescent, Per Package)  (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)					$I_T = (3$	1.6 μΑ/kHz) f 3.1 μΑ/kHz) f 4.7 μΑ/kHz) f	+ I <sub>DD</sub>			μAdc	

<sup>5.</sup> Noise immunity specified for worst-case input combination.

Noise Margin for both "1" and "0" level = 1.0 V min @  $V_{DD}$  = 5.0 V 2.0 V min @  $V_{DD}$  = 10 V

2.5 V min @ V<sub>DD</sub> = 15 V

6. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + 3.5 \text{ x } 10^{-3} (C_L - 50) \text{ V}_{DD}f$$

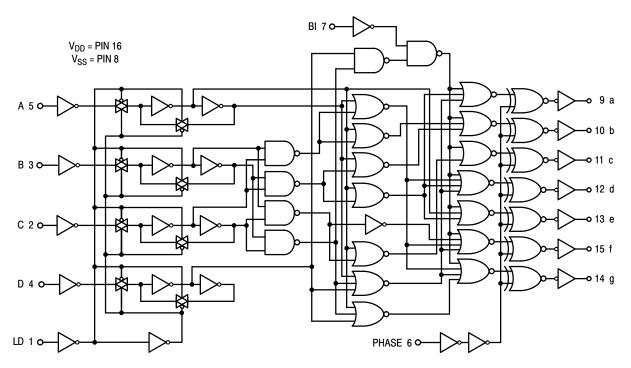
where:  $I_T$  is in  $\mu A$  (per package),  $C_L$  in pF,  $V_{DD}$  in V, and f in kHz is input frequency. 7. The formulas given are for the typical characteristics only at  $25^{\circ}C$ .

# SWITCHING CHARACTERISTICS (8.) $(C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C})$

Characteristic	Symbol	$V_{DD}$	Min	Тур	Max	Unit
Output Rise Time $t_{TLH} = (3.0 \text{ ns/pF}) C_L + 30 \text{ ns}$ $t_{TLH} = (1.5 \text{ ns/pF}) C_L + 15 \text{ ns}$ $t_{TLH} = (1.1 \text{ ns/pF}) C_L + 10 \text{ ns}$	t <sub>TLH</sub>	5.0 10 15	=	100 50 40	200 100 80	ns
Output Fall Time $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns} \\ t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns} \\ t_{THL} = (0.55 \text{ ns/pF}) C_L + 12.5 \text{ ns}$	t <sub>THL</sub>	5.0 10 15	_ _ _	100 50 40	200 100 80	ns
Turn–Off Delay Time $t_{PLH} = (1.7 \text{ ns/pF}) C_L + 520 \text{ ns}$ $t_{PLH} = (0.66 \text{ ns/pF}) C_L + 217 \text{ ns}$ $t_{PLH} = (0.5 \text{ ns/pF}) C_L + 160 \text{ ns}$	t <sub>PLH</sub>	5.0 10 15	_ _ _	605 250 185	1210 500 370	ns
Turn–On Delay Time $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 420 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 172 \text{ ns}$ $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 130 \text{ ns}$	t <sub>PHL</sub>	5.0 10 15	_ _ _	505 205 155	1650 660 495	ns
Setup Time	t <sub>su</sub>	5.0 10 15	350 450 500		_ _ _	ns
Hold Time	t <sub>h</sub>	5.0 10 15	40 30 20		_ _ _	ns
Latch Disable Pulse Width (Strobing Data)	twн	5.0 10 15	250 100 80	125 50 40	_ _ _	ns

<sup>8.</sup> The formulas given are for the typical characteristics only.

# LOGIC DIAGRAM



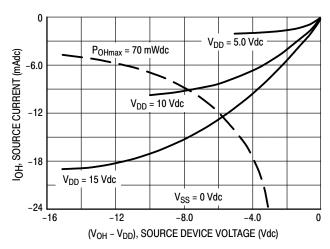
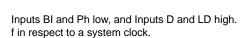


Figure 1. Typical Output Source Characteristics



All outputs connected to respective C<sub>L</sub> loads.

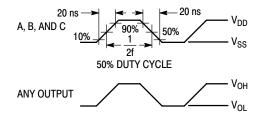


Figure 3. Dynamic Power Dissipation Signal Waveforms

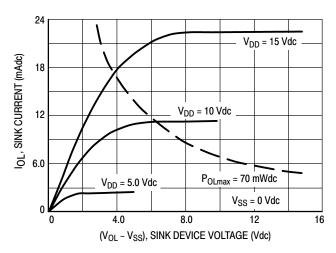
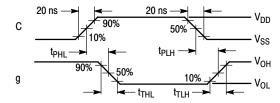
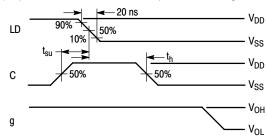


Figure 2. Typical Output Sink Characteristics

(a) Inputs D, Ph, and BI low, and Inputs A, B, and LD high.



(b) Inputs D, Ph, and BI low, and Inputs A and B high.



(c) Data DCBA strobed into latches

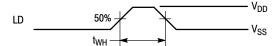


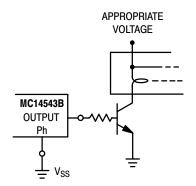
Figure 4. Dynamic Signal Waveforms

#### **CONNECTIONS TO VARIOUS DISPLAY READOUTS**

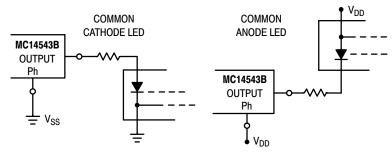
# LIQUID CRYSTAL (LC) READOUT

# ONE OF SEVEN SEGMENTS OUTPUT Ph COMMON BACKPLANE (V<sub>SS</sub> TO V<sub>DD</sub>)

# **INCANDESCENT READOUT**

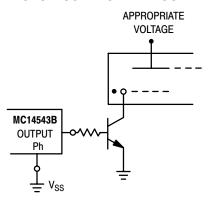


# LIGHT EMITTING DIODE (LED) READOUT



NOTE: Bipolar transistors may be added for gain (for  $V_{DD} \leq 10 \text{ V}$  or  $I_{out} \geq 10 \text{ mA}$ ).

# **GAS DISCHARGE READOUT**



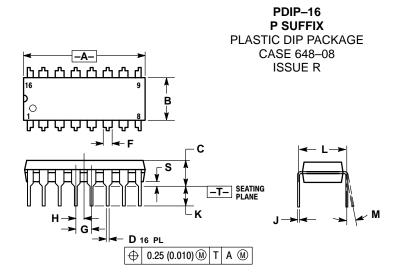
# **CONNECTIONS TO SEGMENTS**

$$e^{\int \frac{a}{g} \int b}$$

 $V_{DD}$  = PIN 16  $V_{SS}$  = PIN 8



#### **PACKAGE DIMENSIONS**



#### NOTES:

- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION LTO CENTER OF LEADS WHEN FORMED PARALLEL.

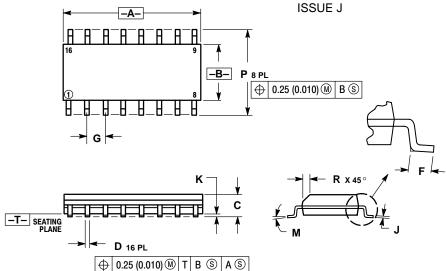
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

  5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS		
DIM	MIN MAX		MIN	MAX		
Α	0.740	0.770	18.80	19.55		
В	0.250	0.270	6.35	6.85		
С	0.145	0.175	3.69	4.44		
D	0.015	0.021	0.39	0.53		
F	0.040	0.70	1.02	1.77		
G	0.100	BSC	2.54	BSC		
Н	0.050	BSC	1.27	BSC		
J	0.008	0.015	0.21	0.38		
K	0.110	0.130	2.80	3.30		
L	0.295	0.305	7.50	7.74		
M	0°	10°	0°	10 °		
S	0.020	0.040	0.51	1.01		



PLASTIC SOIC PACKAGE CASE 751B-05



#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI

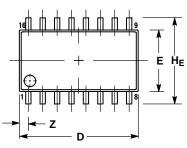
- DIMENSIONING AND TOLERANCING PER ANS Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETER.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  MAXIMUM MOLD PROTRUSION 0.15 (0.006)
  PER SIDE.
  DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

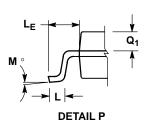
	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050 BSC		
J	0.19	0.25	0.008	0.009	
K	0.10	0.25	0.004	0.009	
M	0°	7°	0°	7°	
P	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

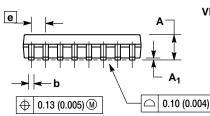
# PACKAGE DIMENSIONS

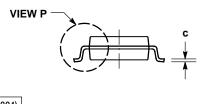
#### SOEIAJ-16 **F SUFFIX**

PLASTIC EIAJ SOIC PACKAGE CASE 966-01 **ISSUE O** 









#### NOTES

- DIMENSIONING AND TOLERANCING PER ANSI Y14 5M 1982
- CONTROLLING DIMENSION: MILLIMETER. I. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE
- MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

  TERMINAL NUMBERS ARE SHOWN FOR
- 4. TEHMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) DAMBAR FAUTUSION STALL BE U.O. (U.U.S) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE
  BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES
DIM	MIN	MIN MAX		MAX
Α		2.05		0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
C	0.18	0.27	0.007	0.011
D	9.90	10.50	0.390	0.413
Ε	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LΕ	1.10	1.50	0.043	0.059
M	0 °	10°	0 °	10°
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z		0.78		0.031

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